

**WHM1822Y****1.8 – 2.3 GHz LOW NOISE WIDE BAND AMPLIFIER****REV A**
January 2011

Key Features



- 1.8 ~ 2.3 GHz
- **0.60 dB Noise Figure**
- 24.0 dBm output IP₃
- 31.0 dB Gain
- 12.0 dBm P_{1dB}
- 1.5:1 VSWR
- Single Power Supply
- RoHS Compliant
- Unconditional Stable, $k > 1$
- RoHS Compliant
- MLS-1 Moisture Sensitivity Level

Product Description

WHM1822Y integrates WanTcom proprietary low noise amplifier technologies, high frequency micro electronic assembly techniques, and high reliability designs to realize optimum low noise figure, wideband, and high performances together. With single +5.0V DC operation, the amplifier has optimal input and output matching in the specified frequency range at 50-Ohm impedance system. The amplifier has standard 0.35" x 0.25" x 0.08" surface mount package.

The amplifier is designed to meet the rugged standard of MIL-STD-883.

Applications

- Mobile Infrastructures
- WiMAX
- 3G
- Security System
- Measurement
- Fixed Wireless

Specifications

Summary of the key electrical specifications at room temperature

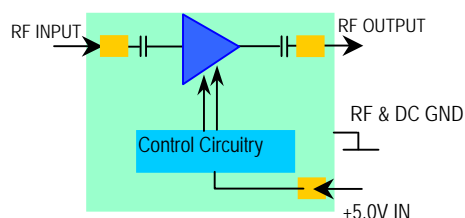
Index	Testing Item	Symbol	Test Constraints	Min	Nom	Max	Unit
1	Gain	S_{21}	1.8 – 2.3 GHz	29	31	33	dB
2	Gain Variation	ΔG	1.8 – 2.3 GHz		+/- 0.5	+/- 1.0	dB
3	Input VSWR	SWR_1	1.8 – 2.3 GHz		1.5:1	1.8:1	Ratio
4	Output VSWR	SWR_2	1.8 – 2.3 GHz		1.35:1	1.5:1	Ratio
5	Reverse Isolation	S_{12}	1.8 – 2.3 GHz		40		dB
6	Noise figure	NF	1.8 – 2.3 GHz		0.60	0.75	dB
7	Output Power 1dB compression Point	P _{1dB}	1.8 – 2.3 GHz	10	12		dBm
8	Output-Third-Order Interception point	IP ₃	Two-Tone, P _{out} = 0 dBm each, 1 MHz separation		24		dBm
9	Current Consumption	I _{dd}	@ 25 °C		45		mA
10	Power Supply Voltage	V _{dd}		+4.7	+5.0	+5.3	V
11	Thermal Resistance	R _{th,c}	Junction to case			220	°C/W
12	Operating Temperature	T _o	Case temperature at the bottom of the housing	-40		+85	°C
13	Maximum Average RF Input Power	P _{IN, MAX}	DC – 13 GHz			10	dBm
14	Spurious	P _{spur}	DC – 13 GHz	-70			dBc

Absolute Maximum Ratings

Parameters	Units	Ratings
DC Power Supply Voltage	V	6.0
Drain Current	mA	70
Total Power Dissipation	mW	400
RF Input Power	dBm	10
Channel Temperature	°C	150
Storage Temperature	°C	-65 ~ 150
Operating Temperature	°C	-40 ~ +85
Thermal Resistance	°C/W	220

Operation of this device beyond any one of these parameters may cause permanent damage.

Functional Block Diagram



Preliminary

Specifications and information are subject to change without notice.

WanTcom, Inc * Phone 01 952 448 6088 * FAX: 01 952 448 7188 * e-mail: sales@wantcominc.com * Web site: www.wantcominc.com



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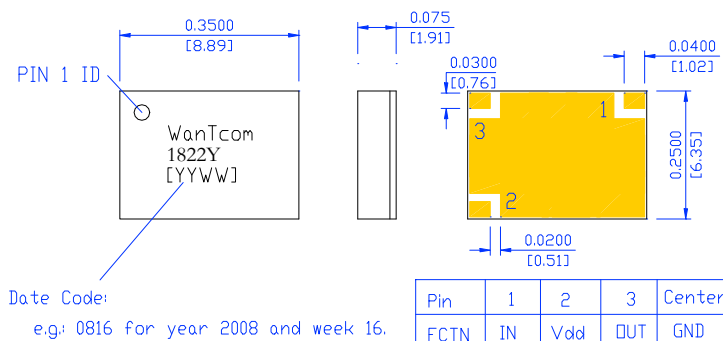
Ordering Information

Model Number	WHM1822Y
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ESD resistance tube of 25 pieces is used for the packing. Contact factory for tape and reel packing option for higher volume order.

Typical Data

Outline



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WanTcom, Inc * Phone 01 952 448 6088 * FAX: 01 952 448 7188 * e-mail: sales@wantcominc.com * Web site: www.wantcominc.com